NXP BYC15-600P diode datasheet

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Hyperfast power diode in a SOD59 (2-lead TO-220AC) plastic package.

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Product data sheet

1. General description

Hyperfast power diode in a SOD59 (2-lead TO-220AC) plastic package.

2. Features and benefits

- Fast switching
- Low leakage current
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses in associated MOSFET or IGBT

3. Applications

- Active PFC in air conditioner
- High frequency switched-mode power supplies
- Continuous Current Mode (CCM) Power Factor Correction (PFC)

4. Quick reference data

Table 1. Qu	ick reference data						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{RRM}	repetitive peak reverse voltage			-	-	600	V
I _{F(AV)}	average forward current	δ = 0.5; T _{mb} ≤ 121 °C; square-wave pulse; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>		-	-	15	A
Static charac	teristics	-	· · ·				
V _F	forward voltage	I _F = 15 A; T _j = 150 °C; <u>Fig. 6</u>		-	1.4	2	V
Dynamic cha	racteristics	·					
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 200 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	13	18	ns





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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	K-K-A
2	А	anode	$2 \circ 4$	001aaa020
mb	mb	mounting base; connected to cathode	C () () () () () () () () () ()	

6. Ordering information

Table 3. Ordering in	formation						
Type number	Package						
	Name	Description	Version				
BYC15-600P	TO-220AC	plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59				

7. Marking

Table 4. Marking codes	
Type number	Marking code
BYC15-600P	BYC15-600P

8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Parameter	Conditions	Min	Max	Unit
repetitive peak reverse voltage		-	600	V
crest working reverse voltage		-	600	V
reverse voltage	DC	-	600	V
average forward current	δ = 0.5; T _{mb} ≤ 121 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3	-	15	A
repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _{mb} ≤ 121 °C; square-wave pulse	-	30	A
	repetitive peak reverse voltage crest working reverse voltage reverse voltage average forward current	repetitive peak reverse voltageDCreverse voltageDCaverage forward current $\delta = 0.5; T_{mb} \le 121 \degree C;$ square-wave pulse; Fig. 1; Fig. 2; Fig. 3repetitive peak forward current $\delta = 0.5; t_p = 25 \ \mu s; T_{mb} \le 121 \degree C;$	repetitive peak reverse voltage-crest working reverse voltage-reverse voltageDCaverage forward current $\delta = 0.5; T_{mb} \le 121 ^{\circ}C;$ square-wave pulse; Fig. 1; Fig. 2; Fig. 3repetitive peak forward current $\delta = 0.5; t_p = 25 \mu s; T_{mb} \le 121 ^{\circ}C;$	repetitive peak reverse voltage-600crest working reverse voltage-600reverse voltageDC-600average forward current $\delta = 0.5; T_{mb} \le 121$ °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3-15repetitive peak forward current $\delta = 0.5; t_p = 25 \ \mu s; T_{mb} \le 121$ °C;-30

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Symbol	Parameter	Conditions	Min	Max	Unit
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	-	180	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	-	200	A
T _{stg}	storage temperature		-65	175	°C
Tj	junction temperature		-	175	°C

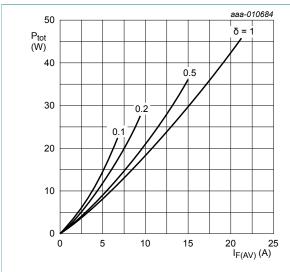
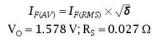
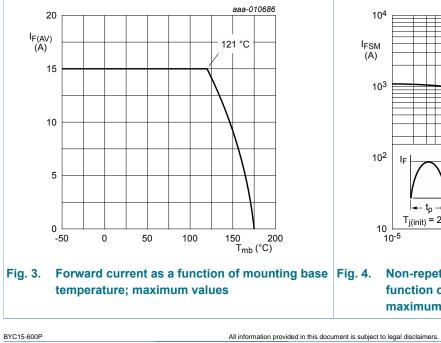


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values





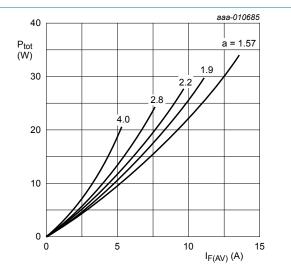
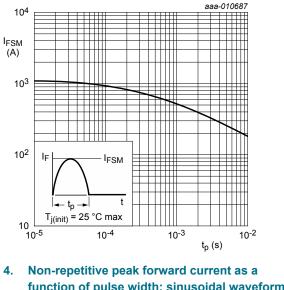


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

a = form factor =
$$I_{F(RMS)} / I_{F(AV)}$$

V₀ = 1.578 V; R_S = 0.027 Ω



function of pulse width; sinusoidal waveform; maximum values

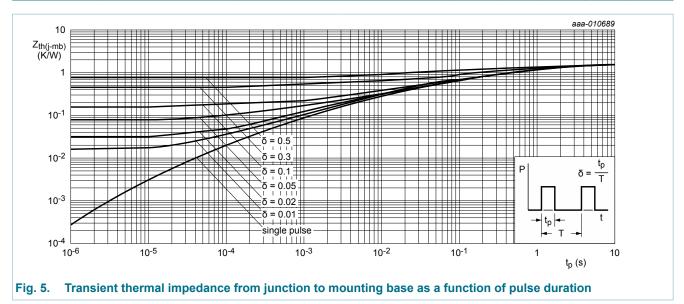
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9. Thermal characteristics

Table 6. The	rmal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	with heatsink compound; Fig. 5	-	-	1.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	60	-	K/W



10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · · · · ·	I.			
V _F	forward voltage	I _F = 15 A; T _j = 25 °C; <u>Fig. 6</u>	-	2.7	3.2	V
		I _F = 15 A; T _j = 150 °C; <u>Fig. 6</u>	-	1.4	2	V
I _R reve	reverse current	V _R = 600 V; T _j = 25 °C	-	-	10	μA
		V _R = 600 V; T _j = 150 °C	-	-	1	mA
Dynamic cl	naracteristics					
Q _r recovered charge		$I_F = 15 \text{ A}; V_R = 200 \text{ V}; dI_F/dt = 200 \text{ A}/$ μ s; T _j = 25 °C; <u>Fig. 7</u>	-	30	-	nC
		I _F = 15 A; V _R = 200 V; dI _F /dt = 200 A/ μs; T _i = 125 °C; <u>Fig. 7</u>	-	115	-	nC

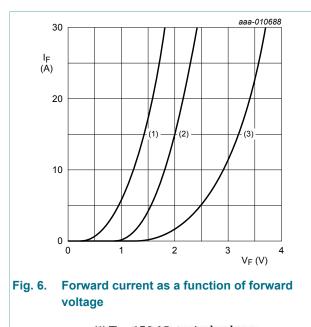
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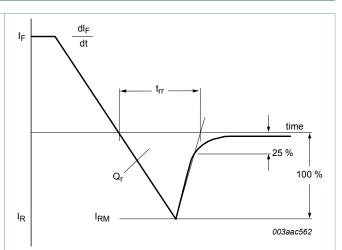
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	13	18	ns
	I_F = 15 A; V_R = 400 V; dI_F/dt = 500 A/ µs; T_j = 25 °C; <u>Fig. 7</u>	-	22	-	ns	
		I _F = 15 A; V _R = 200 V; dI _F /dt = 200 A/ μs; T _j = 25 °C; <u>Fig. 7</u>	-	28	-	ns
		I _F = 15 A; V _R = 200 V; dI _F /dt = 200 A/ μs; T _j = 125 °C; <u>Fig. 7</u>	-	39	-	ns
I _{RM}	peak reverse recovery current	I _F = 15 A; V _R = 200 V; dI _F /dt = 200 A/ μs; T _j = 25 °C; <u>Fig. 7</u>	-	2.1	-	A
		I _F = 15 A; V _R = 200 V; dI _F /dt = 200 A/ μs; T _j = 125 °C; <u>Fig. 7</u>	-	5.8	-	A



(1) $T_j = 150$ °C; typical values; (2) $T_j = 150$ °C; maximum values; (3) $T_j = 25$ °C; maximum values; $V_0 = 1.578$ V; $R_s = 0.027 \Omega$





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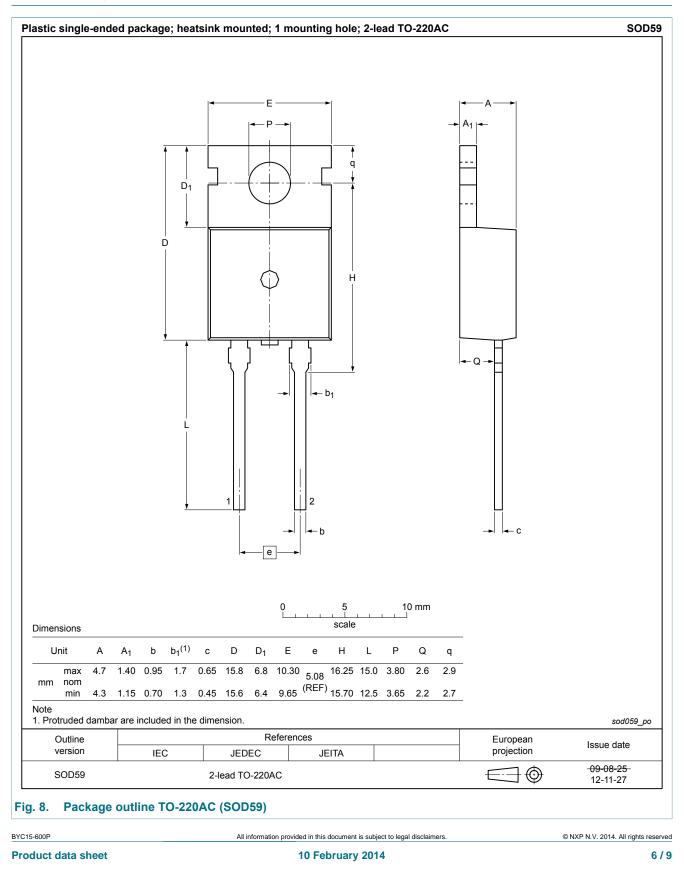
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11. Package outline



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12. Legal information

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Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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